June 2001 Revised February 2002

FAIRCHILD

SEMICONDUCTOR

GTLP1B151 1-Bit LVTTL/GTLP Transceiver with Separate LVTTL Port and Feedback Path

General Description

The GTLP1B151 is a 1-bit transceiver that provides LVTTL-to-GTLP signal level translation. Individual LVTTL and GTLP driver enables are also available. The GTLP1B151 offers separate LVTTL inputs and outputs, and can provide a feedback path for control and diagnostics monitoring.

High-speed backplane operation is a direct result of GTLP's reduced output swing (<1V), reduced input threshold levels and output edge rate control. The edge rate control minimizes bus-settling time. GTLP is a Fairchild Semiconductor derivative of the Gunning Transistor Logic (GTL) JEDEC standard JESD8-3.

Fairchild's GTLP has internal edge-rate control and is process, voltage and temperature compensated. GTLP's I/O structure is similar to GTL and BTL but offers different output levels and receiver threshold. Typical GTLP output voltage levels are: $V_{OL} = 0.5V$, $V_{OH} = 1.5V$, and $V_{REF} = 1V$.

Features

- Separate LVTTL inputs and outputs
- A feedback path for control and diagnostics monitoring
 Bidirectional interface between GTLP and LVTTL logic levels
- Designed with edge rate control circuitry to reduce output noise on the GTLP port
- V_{REF} pin provides external supply reference voltage for receiver threshold adjustibility
- Special PVT compensation circuitry to provide consistent performance over variations of process, supply voltage and temperature
- TTL compatible driver and control inputs
- Designed using Fairchild advanced BiCMOS technology
- Bushold data inputs on A port to eliminate the need for external pull-up resistors for unused inputs
- Power up/down and power off high impedance for live insertion
- Open drain on GTLP to support wired-or connection
- Flow through pinout optimizes PCB layout
- A Port source/sink –24mA / +24mA
- B Port sink +50mA

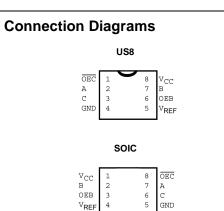
Ordering Code:

Order Number	Package Number	Package Description
GTLP1B151M		8-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow [TUBE]
GTLP1B151MX		8-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow [TAPE and REEL]
GTLP1B151K8X		8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide [TAPE and REEL]

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Pin Descriptions					
Pin Names	Description				
OEB, OEC	LVTTL Individual Output Enable Controls (OEC is Active LOW)				
V_{CC} , GND, V_{REF}	Device Supplies				
A	A Port LVTTL Input				
В	B Port GTLP Input/Output				
С	C Port LVTTL Output				



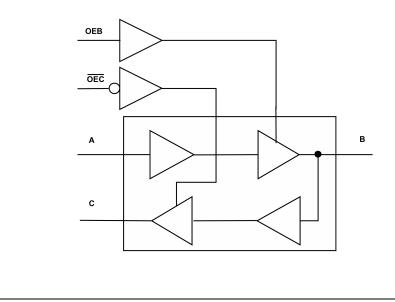
Functional Description

The GTLP1B151 is a 1-bit transceiver that supports GTLP and LVTTL signal levels. Data polarity is non-inverting with separate LVTTL inputs and outputs and there are individual GTLP and LVTTL output enable controls.

Functional Tables

Inputs			Outputs		Description		
OEB	OEC	A _n	B _n	B _n	Cn	Description	
Н	L	L	Output	L	L	B Bus Enabled, C Bus Enabled	
Н	L	Н	Output	Н	Н	B Bus Enabled, C Bus Enabled	
Н	Н	L	Output	L	Z	B Bus Enabled, C Bus Disabled	
Н	Н	Н	Output	Н	Z	B Bus Enabled, C Bus Disabled	
L	Н	L	L	Z	Z	B Bus Disabled, C Bus Disabled	
L	Н	Н	Н	Z	Z	B Bus Disabled, C Bus Disabled	
L	L	N/A	L	Z	L	B Bus Disabled, C Bus Enabled	
L	L	N/A	Н	Z	Н	B Bus Disabled, C Bus Enabled	

Logic Diagram



Absolute	Maximum	Ratings(Note 1)
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Recommended Operating

GTLP1B151

Supply Voltage (V _{CC})	-0.5V to +4.6V	Conditions				
DC Input Voltage (VI)	-0.5V to +4.6V	Supply Voltage V _{CC}	3.15V to 3.45V			
DC Output Voltage (V _O)		Bus Termination Voltage (V _{TT})				
Outputs 3-STATE	-0.5V to +4.6V	GTLP	1.47V to 1.53V			
Outputs Active (Note 2)	-0.5V to +4.6V	V _{REF}	0.98V to 1.02V			
DC Output Sink Current into		Input Voltage (V _I)				
C Port I _{OL}	48 mA	on A Port and Control Pins	0.0V to V_{CC}			
DC Output Source Current from		HIGH Level Output Current (I _{OH})				
C Port I _{OH}	–48 mA	C Port	–24 mA			
DC Output Sink Current into		LOW Level Output Current (I _{OL})				
B Port in the LOW State, I _{OL}	100 mA	C Port	+24 mA			
DC Input Diode Current (I _{IK})		B Port	+50 mA			
V ₁ < 0V	–50 mA	Operating Temperature (T _A)	$-40^{\circ}C$ to $+85^{\circ}C$			
DC Output Diode Current (I _{OK})		Note 1: Absolute Maximum Ratings are those				
V _O < 0V	–50 mA	safety of the device cannot be guaranteed. The device should not be oper- ated at these limits. The parametric values defined in the "Electrical Char- acteristics" table are not guaranteed at the absolute maximum rating. The				
ESD Rating	>2000V					
Storage Temperature (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$	 "Recommended Operating Conditions" table will define the condition actual device operation. 				
		Note 2: I_O Absolute Maximum Rating must be obs	served.			

DC Electrical Characteristics

Over Recommended Operating Free-Air Temperature Range, V_{REF} = 1.0V (unless otherwise noted).

Symbol		Test Conditions		Min	Typ (Note 3)	Max	Units	
VIH	B Port			V _{REF} + 0.05		V _{TT}	V	
	Others			2.0		1	v	
V _{IL}	B Port			0.0		V _{REF} - 0.05	V	
	Others					0.8	v	
V _{REF}	B Port			0.7V	1.0	1.3V	V	
V _{TT}	B Port			V_{REF} + 50 mV	1.5	V _{CC}	V	
V _{IK}		V _{CC} = 3.15V	I _I = -18 mA	t t		-1.2	V	
V _{ОН}	C Port	V _{CC} = Min to Max (Note 4)	I _{OH} = -100 μA	V _{CC} -0.2		1 1		
		V _{CC} = 3.15V	I _{OH} = -8 mA	2.4		1 1	V	
			I _{OH} = -24mA	2.2		1		
V _{OL}	C Port	V _{CC} = Min to Max (Note 4)	I _{OL} = 100 μA			0.2		
		V _{CC} = 3.15V	I _{OL} = 8 mA	t t		0.4	V	
		V _{CC} = 3.15V	$I_{OL} = 24mA$	t t		0.5		
	B Port	V _{CC} = 3.15V	I _{OL} = 40 mA			0.4	V	
			I _{OL} = 50 mA			0.55	v	
II Control Pins	Control Pins	$V_{CC} = 3.45V$	$V_{I} = 3.45V$	t t		5	μA	
			$V_I = 0V$			-5	μΑ	
	A Port	$V_{CC} = 3.45V$	$V_{I} = 3.45V$	t t		10	μA	
			$V_I = 0V$			-10	μΑ	
	B Port	V _{CC} = 3.45V	V _I = 3.45			5		
			$V_I = 0$			-5	μA	
I _{OFF} A d	A or C Ports,	$V_{CC} = 0$	V_{I} or $V_{O} = 0$ to 3.45V	t t		30	μA	
	Control Pins							
	B Port	$V_{CC} = 0$	V_{I} or $V_{O} = 0$ to 3.45V			30	μA	
I _{I (HOLD)}	A Port	V _{CC} = 3.15V	V _I = 0.8V	75		1	μA	
			$V_{I} = 2.0V$			-75	μА	
I _{OZH}	C Port	$V_{CC} = 3.45V$	V _O = 3.45V			10	μA	
	B Port	1	$V_0 = 3.45V$			5	μΛ	
I _{OZL}	C Port	V _{CC} = 3.45V	$V_0 = 0V$			-10	μA	
	B Port	1	$V_{0} = 0.0V$			-5	μΑ	

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DC Electrical Characteristics (Continued)

Min Тур Max Symbol **Test Conditions** Units (Note 3) All Ports $V_{CC} = 0$ to 1.5V $V_{I} = 0$ to 3.45V I_{PU/PD} 30 μΑ $V_{CC} = 3.45V$ Outputs HIGH A or B Ports 11 I_{CC} or C Port $I_{O} = 0$ Outputs LOW 11 mA $V_I = V_{CC}/V_{TT}$ or GND Outputs Disabled 11 ΔI_{CC} A Port and $V_{CC} = 3.45V,$ One Input at V_{CC} 2 mΑ Control Pins (Note 5) A or Control Inputs at V_{CC} or GND -0.6V Ci Control Pins $V_I = V_{CC} \text{ or } 0$ 3 pF and A Port Co C Port $V_I = V_{CC} \text{ or } 0$ 5 pF C_{I/O} B Port $V_I = V_{TT}$ or 0 5.5 pF

Note 3: All typical values are at V_{CC} = 3.3V and T_A = 25°C.

Note 4: For conditions shown as Min, use the appropriate value specified under recommended operating conditions.

Note 5: This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

Note: GTLP V_{REF} and V_{TT} are specified to 2% tolerance since signal integrity and noise margin can be significantly degraded if these supplies are noisy. In addition, V_{TT} and R_{TERM} can be adjusted beyond the recommended operating to accommodate backplane impedances other than 50 Ω , but must remain within the boundaries of the DC Absolute Maximum Ratings. Similarly, V_{REF} can be adjusted to optimize noise margin.

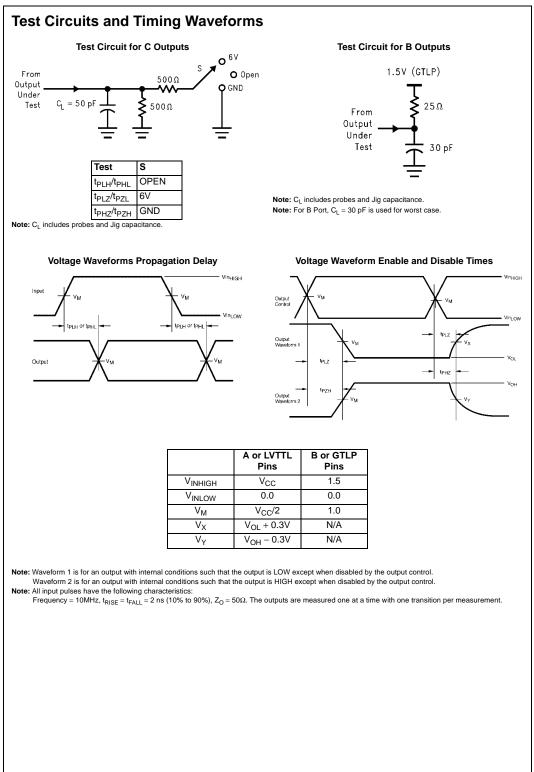
AC Electrical Characteristics

Over recommended range of supply voltage and operating free-air temperature, $V_{REF} = 1.0V$ (unless otherwise noted).

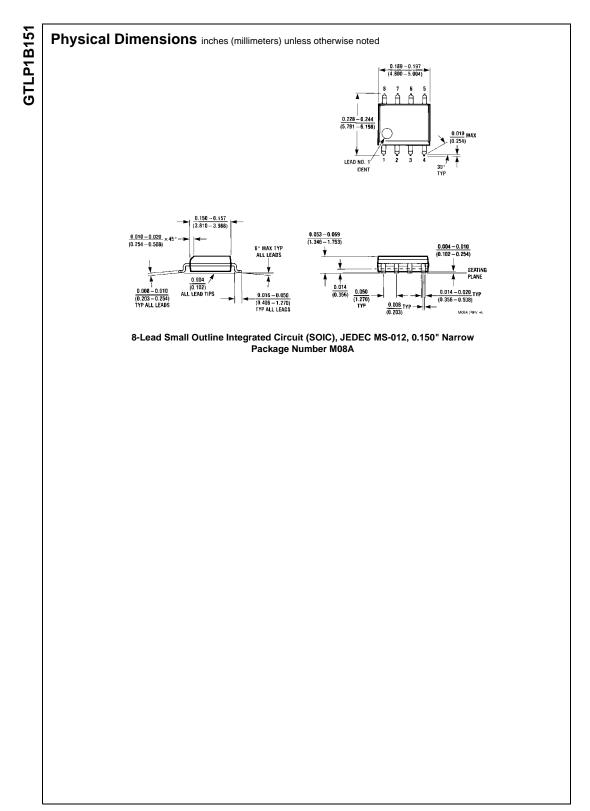
 $C_L = 30 \text{ pF}$ for B Port and $C_L = 50 \text{ pF}$ for C Port.

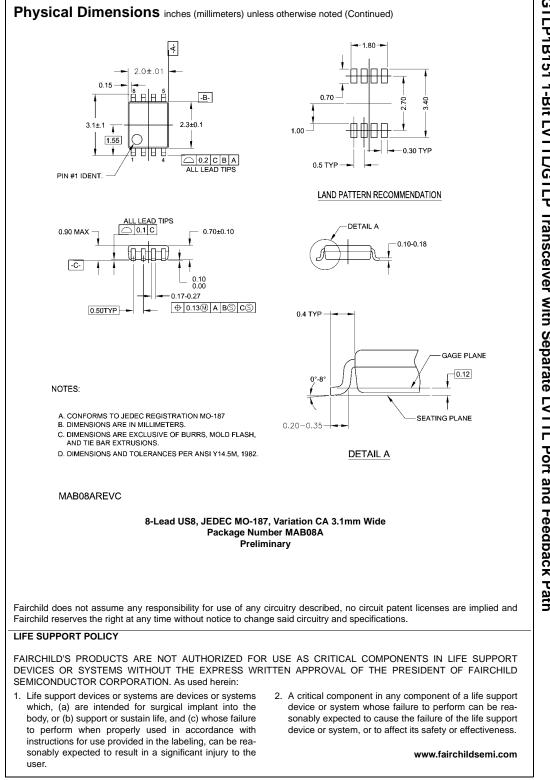
Symbol	From	То	Min	Тур	Max	Unit
	(Input)	(Output)		(Note 6)		Unit
t _{PLH}	А	В	1.2	3.2	7.3	ns
t _{PHL}	A	в	0.8	2.3	4.5	ns
t _{PLH}	В	С	1.4	2.8	4.4	ns
t _{PHL}	В		1.6	2.9	5.0	
t _{PLH}	А	С	1.6	6.0	8.1	ns
t _{PHL}	~		2.0	5.1	7.5	
t _{RISE}	Transition Time, B O		1.4		ns	
t _{FALL}	Transition Time, B O		2.0		ns	
t _{RISE}	Transition Time, C O		2.8		ns	
t _{FALL}	Transition Time, C O	outputs (90% to 10%)		2.5		ns
t _{PZH} , t _{PZL}	050	с	1.2	2.7	5.3	ns
t _{PHZ} , t _{PLZ}	OEC		1.4	2.8	4.9	
t _{PLH}	OEB	В	1.7	3.5	5.9	ns
t _{PHL}	OEB	6	0.5	2.2	4.7	ns

Note 6: All typical values are at $V_{CC} = 3.3V$, and $T_A = 25^{\circ}C$.



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